

## FAST CMOS OCTAL BIDIRECTIONAL TRANSCEIVER

## IDT54/74FCT245T/AT/CT

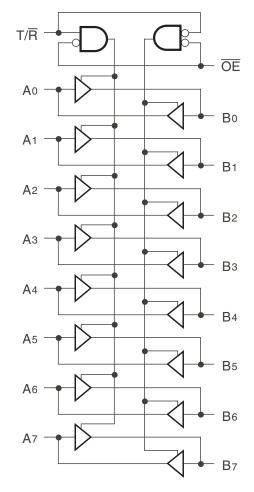
### **FFATURFS**:

- · Std., A, and C grades
- Low input and output leakage ≤1µA (max.)
- CMOS power levels
- · True TTL input and output compatibility:
  - VOH = 3.3V (typ.)
  - -VOL = 0.3V (typ.)
- High Drive outputs (-15mA loн, 64mA loL)
- Meets or exceeds JEDEC standard 18 specifications
- Military product compliant to MIL-STD-883, Class B and DESC listed (dual marked)
- · Power off disable outputs permit "live insertion"
- Available in the following packages:
  - Industrial: SOIC, SSOP, QSOP, TSSOP
  - Military: CERDIP, LCC

## **DESCRIPTION:**

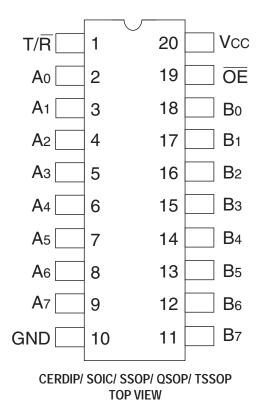
The IDT octal bidirectional transceivers are built using an advanced dual metal CMOS technology. The FCT245T is designed for asynchronous two-way communication between data buses. The transmit/receive ( $T/\overline{R}$ ) input determines the direction of data flow through the bidirectional transceiver. Transmit (active high) enables data from A ports to B ports, and receive (active low) from B ports to A ports. The output enable ( $\overline{OE}$ ) input, when high, disables both A and B ports by placing them in high Z condition.

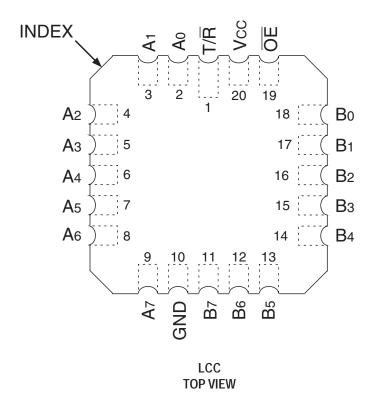
## **FUNCTIONAL BLOCK DIAGRAM**



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## **PIN CONFIGURATION**





## ABSOLUTE MAXIMUM RATINGS(1)

Symbol	Description	Max	Unit
VTERM <sup>(2)</sup>	Terminal Voltage with Respect to GND	-0.5 to +7	V
VTERM <sup>(3)</sup>	Terminal Voltage with Respect to GND	-0.5 to Vcc+0.5	V
Tstg	Storage Temperature	-65 to +150	°C
Іоит	DC Output Current	-60 to +120	mA

#### NOTES:

- 1. Stresses greater than those listed under ABSOLUTE MAXIMUM RATINGS may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect reliability. No terminal voltage may exceed Vcc by +0.5V unless otherwise noted.
- 2. Inputs and Vcc terminals only.
- 3. Output and I/O terminals only.

## CAPACITANCE (TA = +25°C, F = 1.0MHz)

Symbol	Parameter <sup>(1)</sup>	Conditions	Тур.	Max.	Unit
CIN	Input Capacitance	VIN = 0V	6	10	pF
Соит	Output Capacitance	Vout = 0V	8	12	pF

## NOTE:

1. This parameter is measured at characterization but not tested.

## **PIN DESCRIPTION**

Pin Names	Description		
OE Output Enable Inputs (Active LOW)			
T/R Transmit/Recieve Input			
Ao - A7 Side A Inputs or 3-State Outputs			
Bo - B7	Side B Inputs or 3-State Outputs		

## FUNCTION TABLE(1)

Inp	uts	
ŌĒ	T/R	Outputs
L	L	Bus B Data to Bus A
L	Н	Bus A Data to Bus B
Н	Х	High Z State

#### NOTE:

- 1. H = HIGH Voltage Level
  - X = Don't Care
  - L = LOW Voltage Level
  - Z = High Impedance

## DC ELECTRICAL CHARACTERISTICS OVER OPERATING RANGE

Following Conditions Apply Unless Otherwise Specified:

Industrial: TA = -40°C to +85°C, Vcc =  $5.0V \pm 5\%$ ; Military: TA = -55°C to +125°C, Vcc =  $5.0V \pm 10\%$ 

Symbol	Parameter	Test Condit	ions <sup>(1)</sup>	Min.	Typ. <sup>(2)</sup>	Max.	Unit
VIH	Input HIGH Level	Guaranteed Logic HIGH Level		2	_	_	V
VIL	Input LOW Level	Guaranteed Logic LOW Level		_	_	0.8	V
Iн	Input HIGH Current <sup>(4)</sup>	Vcc = Max.	VI = 2.7V	_	_	±1	μA
lıL	Input LOW Current <sup>(4)</sup>	Vcc = Max.	VI = 0.5V	_	_	±1	μA
lozн	High Impedance Output Current	Vcc = Max	Vo = 2.7V	-	_	±1	μA
lozl	(3-State output pins) <sup>(4)</sup>	Vo = 0.5V		1	_	±1	
lı	Input HIGH Current <sup>(4)</sup>	Vcc = Max., Vi = Vcc (Max.)	Vcc = Max., VI = Vcc (Max.)		_	±1	μA
VIK	Clamp Diode Voltage	VCC = Min, I <sub>IN</sub> = -18mA		_	-0.7	-1.2	V
VH	Input Hysteresis				200		mV
Icc	Quiescent Power Supply Current	Vcc = Max., Vin = GND or Vcc		_	0.01	1	mA

## **OUTPUT DRIVE CHARACTERISTICS**

Symbol	Parameter	Test Conditions <sup>(1)</sup>			Typ. <sup>(2)</sup>	Max.	Unit
Vон	Output HIGH Voltage	Vcc = Min	Iон = -6mA MIL	2.4	3.3	_	
		VIN = VIH or VIL	IOH = -8mA IND				V
			IOH = -12mA MIL	2	3	_	
			Iон = -15mA IND				
Vol	Output LOW Voltage	Vcc = Min	IOL = 48mA MIL	_	0.3	0.55	V
		VIN = VIH or VIL	IOL = 64mA IND				
los	Short Circuit Current	$Vcc = Max., Vo = GND^{(3)}$		-60	-120	-225	mA

#### NOTES

- 1. For conditions shown as Min. or Max., use appropriate value specified under Electrical Characteristics for the applicable device type.
- 2. Typical values are at Vcc = 5.0V, +25°C ambient.
- 3. Not more than one output should be tested at one time. Duration of the test should not exceed one second.
- 4. The test limit for this parameter is  $\pm 5\mu A$  at  $T_A = -55$ °C.

## POWER SUPPLY CHARACTERISTICS

Symbol	Parameter	Test Conditions <sup>(1)</sup>		Min.	Typ. <sup>(2)</sup>	Max.	Unit
Δlcc	Quiescent Power Supply Current TTL Inputs HIGH	$Vcc = Max.$ $Vin = 3.4V^{(3)}$		_	0.5	2	mA
ICCD	Dynamic Power Supply Current <sup>(4)</sup>	Vcc = Max. Outputs Open  OE = T/R = GND One Input Toggling 50% Duty Cycle	VIN = VCC VIN = GND	ı	0.15	0.25	mA/ MHz
Ic	Total Power Supply Current <sup>(6)</sup>	Vcc = Max. Outputs Open fi = 10MHz	VIN = VCC VIN = GND	_	1.5	3.5	mA
		50% Duty Cycle $\overline{OE} = T/\overline{R} = GND$ One Bit Toggling	VIN = 3.4V VIN = GND	_	1.8	4.5	
		Vcc = Max. Outputs Open fi = 2.5MHz	VIN = VCC VIN = GND	_	3	6(5)	
		50% Duty Cycle  OE = T/R = GND  Eight Bits Toggling	VIN = 3.4V VIN = GND	_	5	14(5)	

#### NOTES:

- 1. For conditions shown as Min. or Max., use appropriate value specified under Electrical Characteristics for the applicable device type.
- 2. Typical values are at Vcc = 5.0V, +25°C ambient.
- 3. Per TTL driven input; (VIN = 3.4V). All other inputs at Vcc or GND.
- 4. This parameter is not directly testable, but is derived for use in Total Power Supply Calculations.
- 5. Values for these conditions are examples of Δlcc formula. These limits are guaranteed but not tested.
- 6. IC = IQUIESCENT + INPUTS + IDYNAMIC
  - $IC = ICC + \Delta ICC DHNT + ICCD (fcP/2+ fiNi)$
  - Icc = Quiescent Current
  - $\Delta$ lcc = Power Supply Current for a TTL High Input (VIN = 3.4V)
  - DH = Duty Cycle for TTL Inputs High
  - NT = Number of TTL Inputs at DH
  - ICCD = Dynamic Current caused by an Input Transition Pair (HLH or LHL)
  - fcp = Clock Frequency for Register Devices (Zero for Non-Register Devices)
  - fi = Output Frequency
  - Ni = Number of Outputs at fi
- All currents are in milliamps and all frequencies are in megahertz.

## SWITCHING CHARACTERISTICS OVER OPERATING RANGE - INDUSTRIAL

			74FCT245AT 74FCT245CT		245CT		
Symbol	Parameter	Condition <sup>(1)</sup>	Min. <sup>(2)</sup>	Max.	Min. <sup>(2)</sup>	Max.	Unit
<b>t</b> PLH	Propagation Delay	CL = 50pF	1.5	4.6	1.5	4.1	ns
tPHL	A to B, B to A	$RL = 500\Omega$					
tpzh	Output Enable Time		1.5	6.2	1.5	5.8	ns
tPZL	OE to A or B						
tphz	Output Disable Time		1.5	5	1.5	4.8	ns
tPLZ	OE to A or B						
tpzh	Output Enable Time		1.5	6.2	1.5	5.8	ns
tPZL	$T/\overline{R}$ to A or $B^{(3)}$						
tphz	Output Disable Time	]	1.5	5	1.5	4.8	ns
tPLZ	$T/\overline{R}$ to A or $B^{(3)}$						

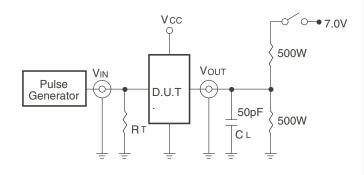
## SWITCHING CHARACTERISTICS OVER OPERATING RANGE - MILITARY

			54FCT245T		54FCT245AT 54FCT245CT		245CT		
Symbol	Parameter	Condition <sup>(1)</sup>	Min. <sup>(2)</sup>	Max.	Min. <sup>(2)</sup>	Max.	Min. <sup>(2)</sup>	Max.	Unit
tplH	Propagation Delay	CL = 50pF	1.5	7.5	1.5	4.9	1.5	4.5	ns
<b>t</b> PHL	A to B, B to A	$RL = 500\Omega$							
tpzh	Output Enable Time		1.5	10	1.5	6.5	1.5	6.2	ns
tPZL	OE to A or B								
tphz	Output Disable Time		1.5	10	1.5	6	1.5	5.2	ns
tplz	OE to A or B								
tpzh	Output Enable Time		1.5	10	1.5	6.5	1.5	6.2	ns
tpzl	T/R to A or B <sup>(3)</sup>								
tphz	Output Disable Time		1.5	10	1.5	6	1.5	5.2	ns
tPLZ	$T/\overline{R}$ to A or $B^{(3)}$								

### NOTES:

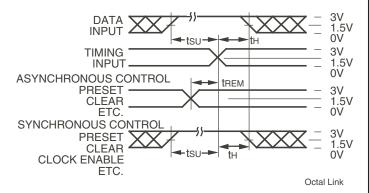
- 1. See test circuit and waveforms.
- 3. This parameter is guaranteed but not tested.

TEST CIRCUITS AND WAVEFORMS

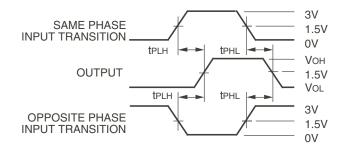


Test Circuits for All Outputs

Octal Link



Set-Up, Hold, and Release Times



Propagation Delay

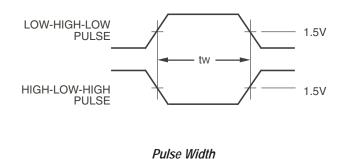
## **SWITCH POSITION**

Test	Switch
Open Drain Disable Low Enable Low	Closed
All Other Tests	Open

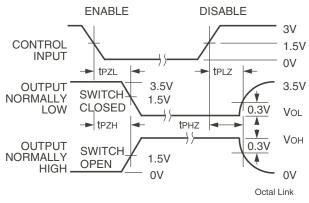
#### **DEFINITIONS:**

CL = Load capacitance: includes jig and probe capacitance.

RT = Termination resistance: should be equal to ZouT of the Pulse Generator.



Octal Link



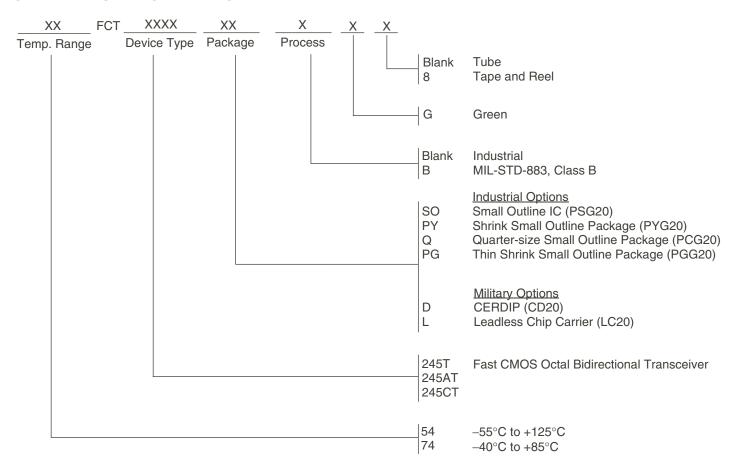
Enable and Disable Times

### NOTES:

Octal Link

- 1. Diagram shown for input Control Enable-LOW and input Control Disable-HIGH.
- 2. Pulse Generator for All Pulses: Rate  $\leq$  1.0MHz; tF  $\leq$  2.5ns; tR  $\leq$  2.5ns.

## ORDERING INFORMATION



# Datasheet Document History

09/29/2009 Pg. 7 Updated the ordering information by removing the "IDT" notation and non RoHS part.

12/12/2016 Pg. 7 Updated the ordering information by adding detailed package information and Tape & Reel.

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